

Supporting Information for

Gallium-Doped Zinc Oxide Semiconductor Nanoparticles for Plasmonic Applications: A Combined Experimental and Computational Study

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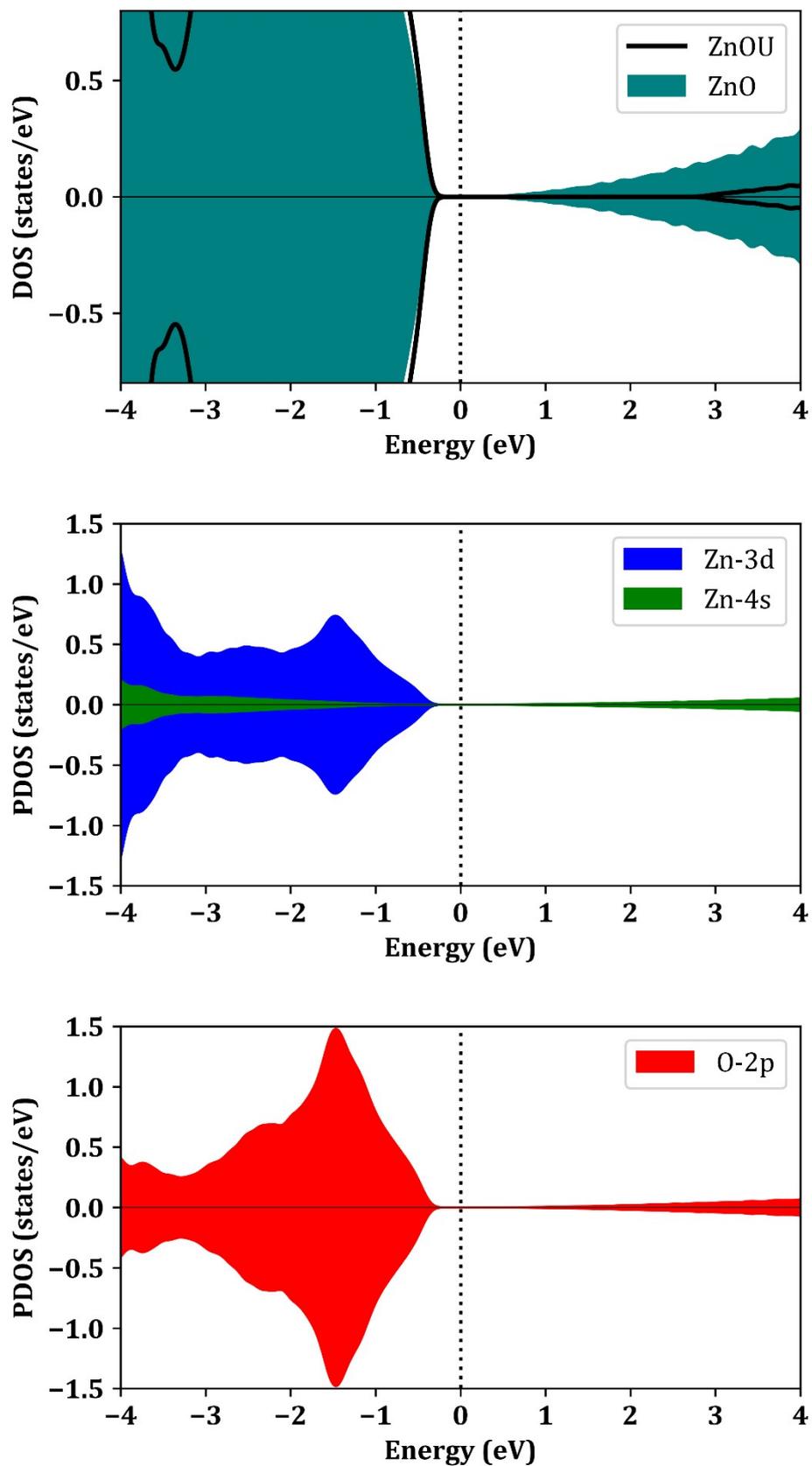


Figure S1. Projected and total density of states (PDOS/TDOS) for pristine ZnO

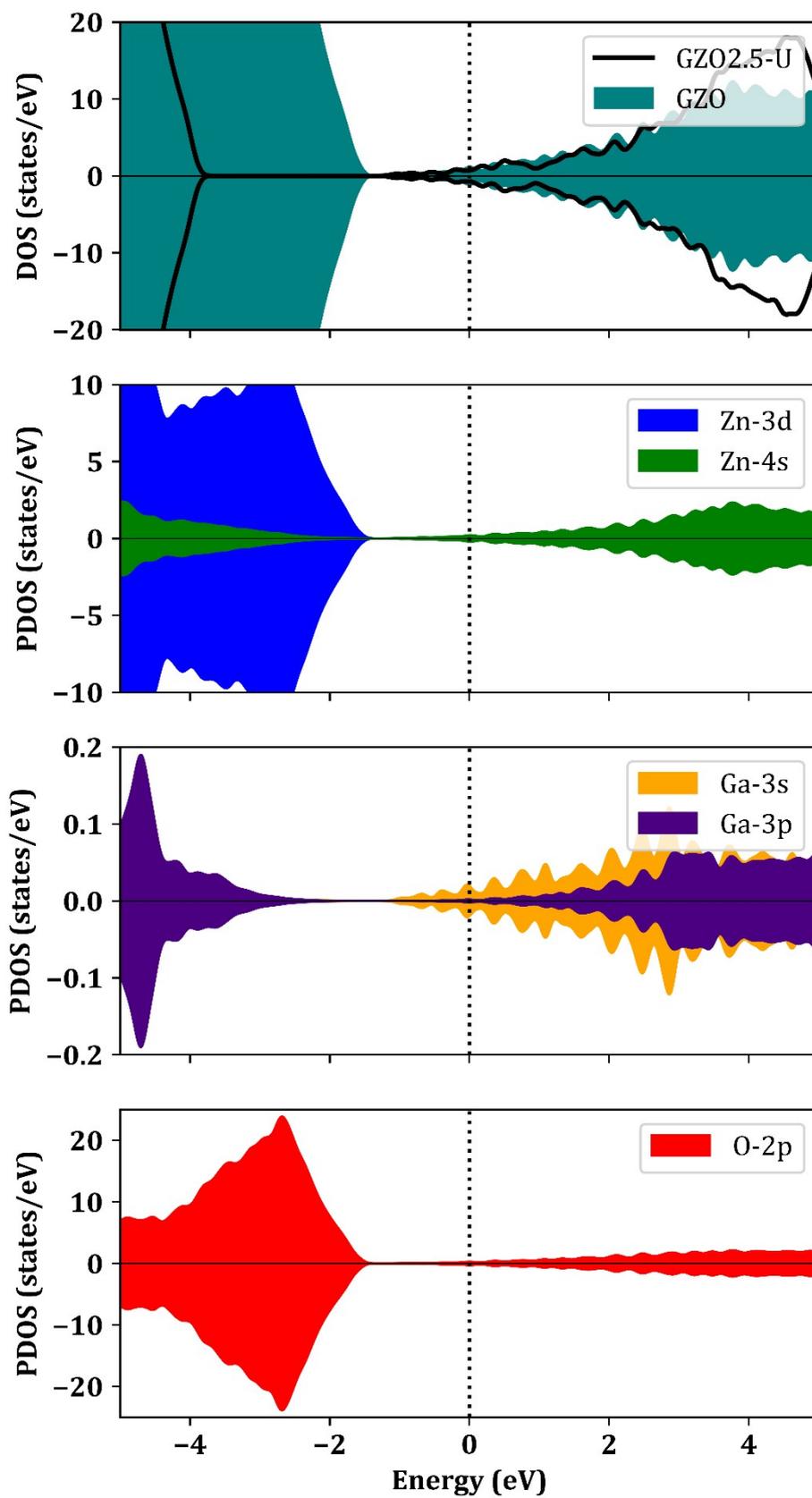


Figure S2. Projected and total density of states (PDOS/TDOS) for GZO_{2.5}

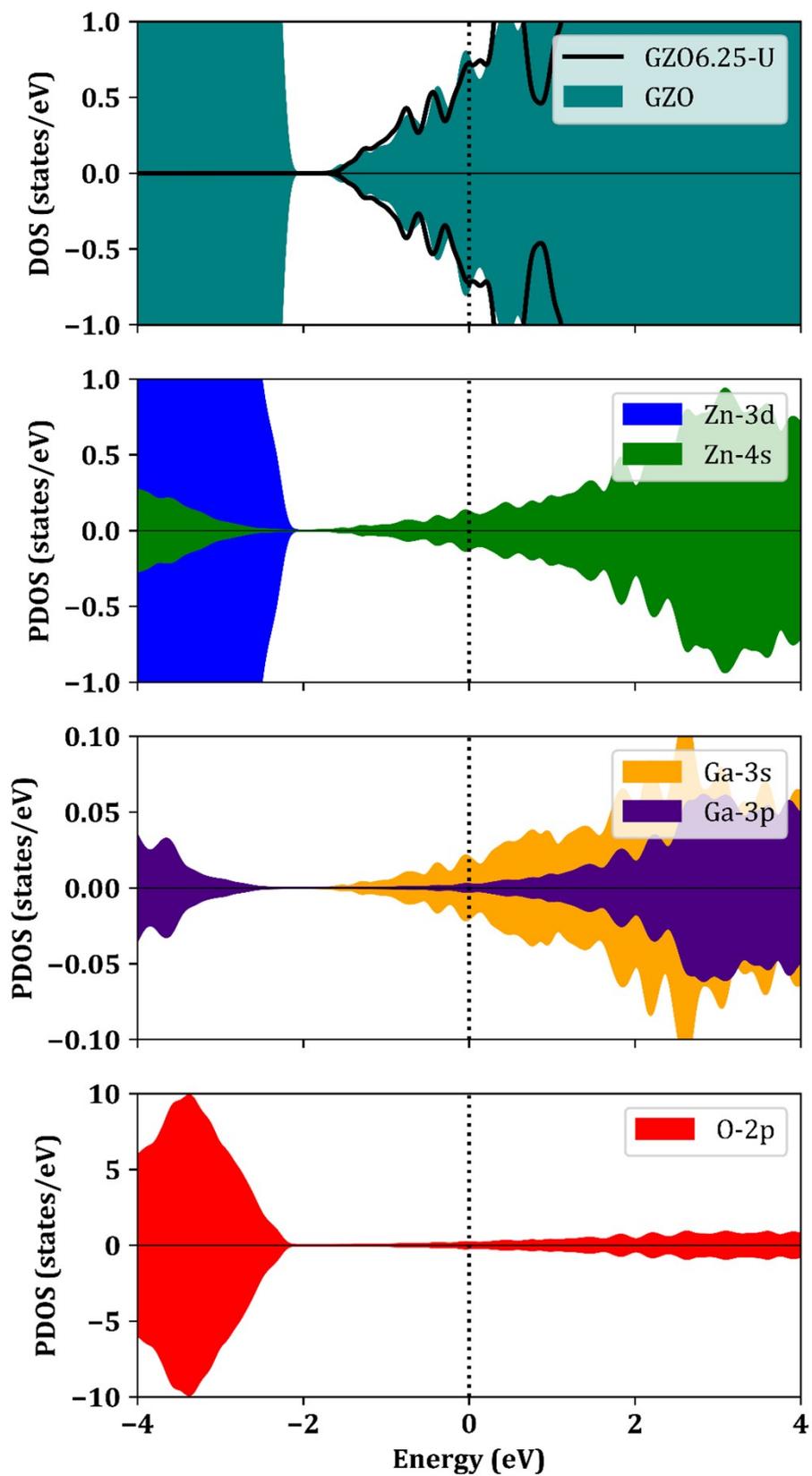


Figure S3. Projected and total density of states (PDOS/TDOS) for GZO6.25.